

MOS FIELD EFFECT POWER TRANSISTOR 2SK1594

SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

DESCRIPTION

The 2SK1594 is N-channel MOS Field Effect Transistor designed for solenoid, motor and lamp driver.

FEATURES

- Low On-state Resistance
 - $R_{DS(on)} \leqq 0.080~\Omega$ (Vgs = 4 V, ID = 10 A)

RDS(on) $\leq 0.045 \Omega$ (VGS = 10 V, ID = 10 A)

- Low Ciss Ciss = 1 200 pF TYP.
- Built-in G-S Gate Protection Diode

QUALITY GRADE

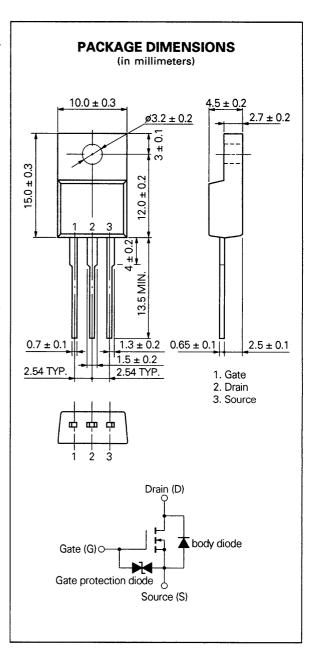
Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C)

Drain to Source Voltage	Voss	30	V
Gate to Source Voltage	VGSS (A	e) ±20	٧
Drain Current (DC)	D(DC)	±20	Α
Drain Current (pulse)	D(pulse)	* ±80	Α
Total Power Dissipation (Tc = 25 °C)	P _{T1}	30	W
Total Power Dissipation (Ta = 25 °C)	P _{T2}	2.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	T_{stg}	-55 to +150	°C

* PW \leq 10 μ s, Duty Cycle \leq 2 %

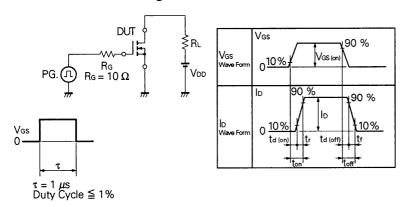




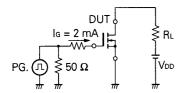
ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain to Source On-state Resistance	RDS(on)		0.045	0.08	Ω	Vgs = 4 V, lp = 10 A
Drain to Source On-state Resistance	Ros(on)		0.03	0.045	Ω	Vgs = 10 V, Ip = 10 A
Gate to Source Cutoff Voltage	V _{GS(off)}	1.0		2.5	٧	Vps = 10 V, lp = 1 mA
Forward Transfer Admittance	yfs	7			S	Vps = 10 V, lp = 10 A
Drain Leakage Current	loss			10	μΑ	Vps = 30 V, Vgs = 0
Gate to Source Leakage Current	lgss			±10	μΑ	Vgs = ±20 V, Vps = 0
Input Capacitance	Ciss		1 200		pF	Vps = 10 V
Output Capacitance	Coss		750		pF	V _{GS} = 0 f = 1 MHz
Reverse Transfer Capacitance	Crss		280		pF	
Turn-On Delay Time	td(on)		30		ns	$V_{GS(on)} = 10 \text{ V}$ $V_{DD} = 15 \text{ V}$ $I_{D} = 10 \text{ A}, R_{G} = 10 \Omega$ $R_{L} = 1.5 \Omega$
Rise Time	tr		360		ns	
Turn-Off Delay Time	td(off)		190		ns	
Fall Time	tr		220		ns	
Total Gate Charge	Qg		35		nC	Vos = 10 V lo = 20 A
Gate to Source Charge	Qgs		4		nC	
Gate to Drain Charge	Qgp		12		nC	V _{DD} = 30 V
Diode Forward Voltage	Vsp		1.0		٧	IF = 20 A, VGS = 0
Reverse Recovery Time	trr		110		ns	IF = 20 A, Vgs = 0
Reverse Recovery Charge	Qrr		200		nC	di/dt = 50 A/μs

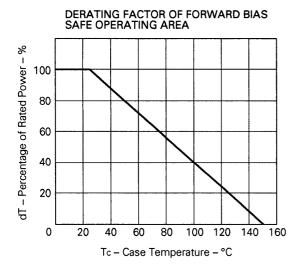
Test Circuit 1: Switching Time



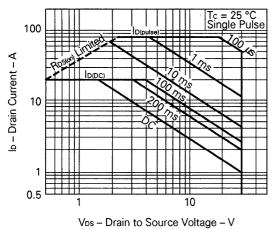
Test Circuit 2: Gate Charge

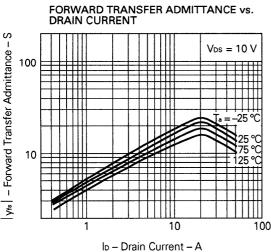


TYPICAL CHARACTERISTICS (Ta = 25 °C)

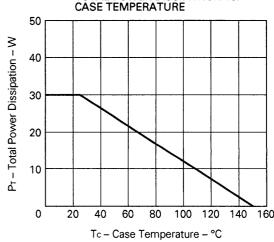




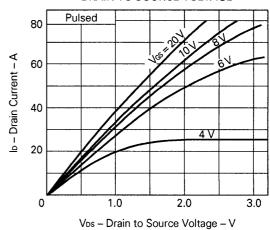




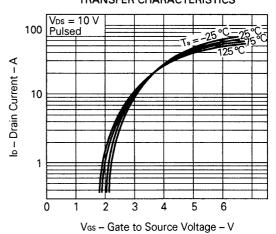
TOTAL POWER DISSIPATION vs. CASE TEMPERATURE

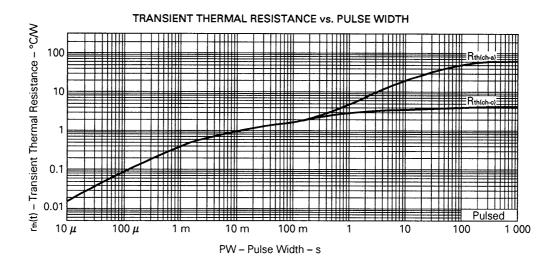


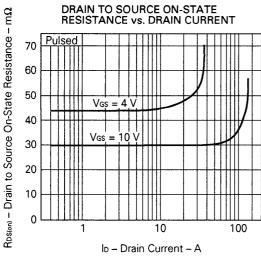
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE

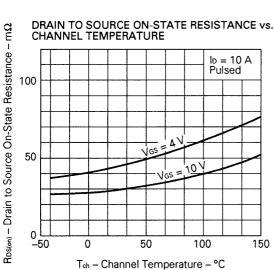


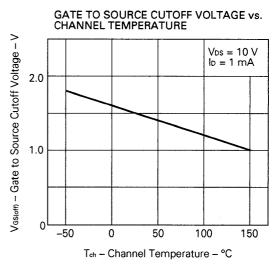
TRANSFER CHARACTERISTICS

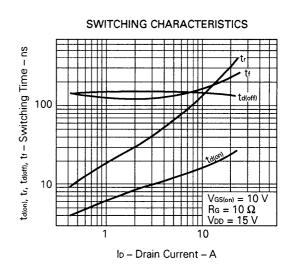


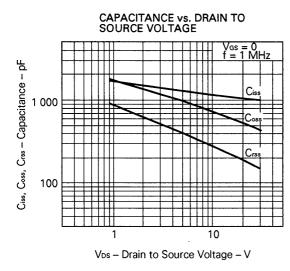


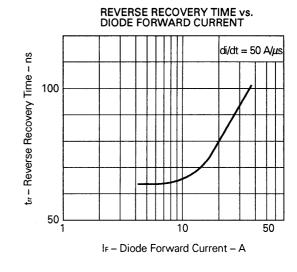














Reference

Application note name	No.
Safe operating area of Power MOS FET.	TEA-1034
Application circuit using Power MOS FET.	TEA-1035
Quality control of NEC semiconductors devices.	TEI-1202
Quality control guide of semiconductors devices.	MEI-1202
Assembly manual of semiconductors devices.	IEI-1207

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